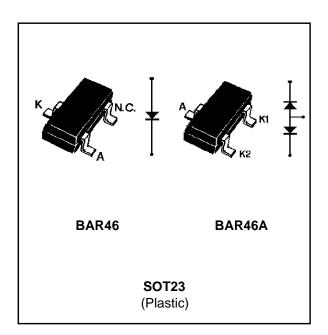


SMALL SIGNAL SCHOTTKY DIODES



DESCRIPTION

High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.

ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	100	V	
Ptot	Power Dissipation *	Tamb=25°C	200	mW
Tstg Tj	Storage and Junction Temperature Range		- 55 to + 150 150	°C

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction-ambient *	625	°C/W
Rth(j-SR)	Junction-Substrate	400	°C/W

^{*} Mounted on ceramic substrate: 7 x 5 x 0.5mm

September 1993

BAR46/BAR46A

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

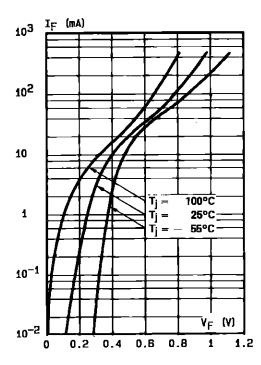
Symbol	Test conditions		Min.	Тур.	Max.	Unit
V_{BR}	Tj = 25 °C	I _R = 100 μA	100			V
V _F *	Tj = 25 °C	I _F = 0.1 mA			0.25	V
	Tj = 25 °C	I _F = 10 mA			0.45	
	Tj = 25 °C	I _F = 250 mA			1	
I _R *	Tj = 25 °C	V _R = 1.5 V			0.5	μΑ
	Tj = 60 °C				5	
	Tj = 25 °C	V _R = 10 V			0.8	
	Tj = 60 °C				7.5	
	Tj = 25 °C	V _R = 50 V			2	
	Tj = 60 °C				15	
	Tj = 25 °C	V _R = 75 V			5	
	Tj = 60 °C				20	

^{*} Pulse test : tp \leq 300 μ s δ < 2%

DYNAMIC CHARACTERISTICS

Symbol	Test conditions		Min.	Тур.	Max.	Unit	
С	Tj = 25 °C	$V_R = 0 V$	f = 1MHz		10		pF
	Tj = 25 °C	V _R = 1 V			6		

Туре	BAR46	BAR46A		
Marking	S46	A46		



rig.1 - Forward current versus forward voltage at different temperatures (typical values).

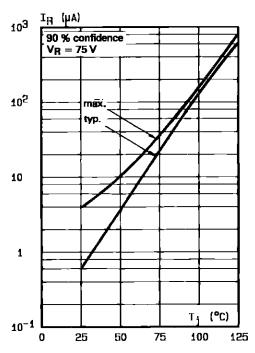


Fig.3 - Reverse current versus junction temperature (typical values).

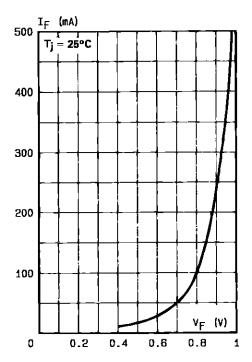


Fig.2 - Forward current versus forward voltage (typical values).

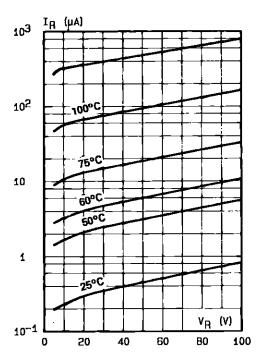


Fig.4 - Reverse current versus continuous reverse voltage

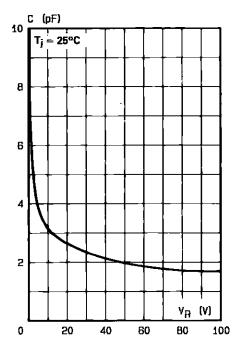


Fig.5 - Capacitance C versus reverse applied voltage $V_{\rm B}$ (typical values).

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